

## LM2930 3-Terminal Positive Regulator

### General Description

The LM2930 3-terminal positive regulator features an ability to source 150 mA of output current with an input-output differential of 0.6V or less. Efficient use of low input voltages obtained, for example, from an automotive battery during cold crank conditions, allows 5V circuitry to be properly powered with supply voltages as low as 5.6V. Familiar regulator features such as current limit and thermal overload protection are also provided.

Designed originally for automotive applications, the LM2930 and all regulated circuitry are protected from reverse battery installations or 2 battery jumps. During line transients, such as a load dump (40V) when the input voltage to the regulator can momentarily exceed the specified maximum operating voltage, the regulator will automatically shut down to protect both internal circuits and the load. The LM2930 cannot be harmed by temporary mirror-image insertion.

Fixed outputs of 5V and 8V are available in the plastic TO-220 and TO-263 power packages.

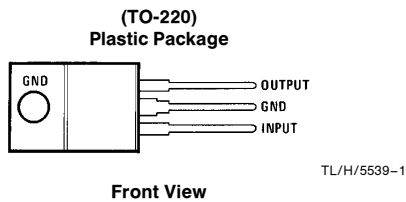
### Features

- Input-output differential less than 0.6V
- Output current in excess of 150 mA
- Reverse battery protection
- 40V load dump protection
- Internal short circuit current limit
- Internal thermal overload protection
- Mirror-image insertion protection
- P<sup>+</sup> Product Enhancement tested

### Voltage Range

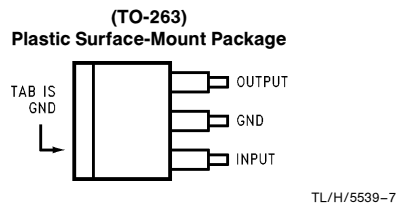
LM2930T-5.0	5V
LM2930T-8.0	8V
LM2930S-5.0	5V
LM2930S-8.0	8V

### Connection Diagrams



Front View

Order Number LM2930T-5.0 or LM2930T-8.0  
See NS Package Number T03B



Top View



Side View

Order Number LM2930S-5.0 or LM2930S-8.0  
See NS Package Number TS3B

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

### Input Voltage

Operating Range	26V
Overvoltage Protection	40V
Reverse Voltage (100 ms)	-12V
Reverse Voltage (DC)	-6V

Internal Power Dissipation (Note 1)

Internally Limited

Operating Temperature Range

-40°C to +85°C

Maximum Junction Temperature

125°C

Storage Temperature Range

-65°C to +150°C

Lead Temp. (Soldering, 10 seconds)

230°C

## Electrical Characteristics (Note 2)

LM2930-5.0  $V_{IN} = 14V$ ,  $I_O = 150$  mA,  $T_J = 25^\circ C$  (Note 5),  $C_2 = 10$   $\mu F$ , unless otherwise specified

Parameter	Conditions	Typ	Tested Limit (Note 3)	Design Limit (Note 4)	Unit
Output Voltage		5	5.3 4.7		$V_{MAX}$ $V_{MIN}$
	$6V \leq V_{IN} \leq 26V$ , $5 mA \leq I_O \leq 150 mA$ $-40^\circ C \leq T_J \leq 125^\circ C$			5.5 4.5	$V_{MAX}$ $V_{MIN}$
Line Regulation	$9V \leq V_{IN} \leq 16V$ , $I_O = 5 mA$	7	25		$mV_{MAX}$
	$6V \leq V_{IN} \leq 26V$ , $I_O = 5 mA$	30	80		$mV_{MAX}$
Load Regulation	$5 mA \leq I_O \leq 150 mA$	14	50		$mV_{MAX}$
Output Impedance	$100 mA_{DC}$ & $10 mA_{rms}$ , 100 Hz – 10 kHz	200			$m\Omega$
Quiescent Current	$I_O = 10 mA$	4	7		$mA_{MAX}$
	$I_O = 150 mA$	18	40		$mA_{MAX}$
Output Noise Voltage	10 Hz – 100 kHz	140			$\mu V_{rms}$
Long Term Stability		20			mV/1000 hr
Ripple Rejection	$f_O = 120 Hz$	56			dB
Current Limit		400	700 150		$mA_{MAX}$ $mA_{MIN}$
Dropout Voltage	$I_O = 150 mA$	0.32	0.6		$V_{MAX}$
Output Voltage Under Transient Conditions	$-12V \leq V_{IN} \leq 40V$ , $R_L = 100\Omega$		5.5 -0.3		$V_{MAX}$ $V_{MIN}$

## Electrical Characteristics (Note 2)

LM2930-8.0 ( $V_{IN} = 14V$ ,  $I_O = 150$  mA,  $T_J = 25^\circ C$  (Note 5),  $C_2 = 10$   $\mu F$ , unless otherwise specified)

Parameter	Conditions	Typ	Tested Limit (Note 3)	Design Limit (Note 4)	Unit
Output Voltage		8	8.5 7.5		$V_{MAX}$ $V_{MIN}$
	$9.4V \leq V_{IN} \leq 26V$ , $5 mA \leq I_O \leq 150 mA$ , $-40^\circ C \leq T_J \leq 125^\circ C$			8.8 7.2	$V_{MAX}$ $V_{MIN}$
Line Regulation	$9.4V \leq V_{IN} \leq 16V$ , $I_O = 5 mA$	12	50		$mV_{MAX}$
	$9.4V \leq V_{IN} \leq 26V$ , $I_O = 5 mA$	50	100		$mV_{MAX}$
Load Regulation	$5 mA \leq I_O \leq 150 mA$	25	50		$mV_{MAX}$
Output Impedance	$100 mA_{DC}$ & $10 mA_{rms}$ , 100 Hz – 10 kHz	300			$m\Omega$
Quiescent Current	$I_O = 10 mA$	4	7		$mA_{MAX}$
	$I_O = 150 mA$	18	40		$mA_{MAX}$
Output Noise Voltage	10 Hz – 100 kHz	170			$\mu V_{rms}$
Long Term Stability		30			mV/1000 hr
Ripple Rejection	$f_O = 120 Hz$	52			dB
Current Limit		400	700 150		$mA_{MAX}$ $mA_{MIN}$
Dropout Voltage	$I_O = 150 mA$	0.32	0.6		$V_{MAX}$
Output Voltage Under Transient Conditions	$-12V \leq V_{IN} \leq 40V$ , $R_L = 100\Omega$		8.8 -0.3		$V_{MAX}$ $V_{MIN}$

**Note 1:** Thermal resistance without a heat sink for junction to case temperature is 3°C/W and for case to ambient temperature is 50°C/W for the TO-220, 73°C/W for the TO-263. If the TO-263 package is used, the thermal resistance can be reduced by increasing the P.C. board copper area thermally connected to the package. Using 0.5 square inches of copper area,  $\theta_{JA}$  is 50°C/W; with 1 square inch of copper area,  $\theta_{JA}$  is 37°C/W; and with 1.6 or more square inches of copper area,  $\theta_{JA}$  is 32°C/W.

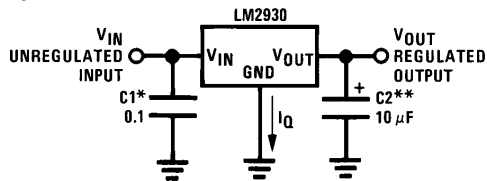
**Note 2:** All characteristics are measured with a capacitor across the input of 0.1  $\mu$ F and a capacitor across the output of 10  $\mu$ F. All characteristics except noise voltage and ripple rejection ratio are measured using pulse techniques ( $t_W \leq 10$  ms, duty cycle  $\leq 5\%$ ). Output voltage changes due to changes in internal temperature must be taken into account separately.

**Note 3:** Guaranteed and 100% production tested.

**Note 4:** Guaranteed (but not 100% production tested) over the operating temperature and input current ranges. These limits are not used to calculate outgoing quality levels.

**Note 5:** To ensure constant junction temperature, low duty cycle pulse testing is used.

## Typical Application

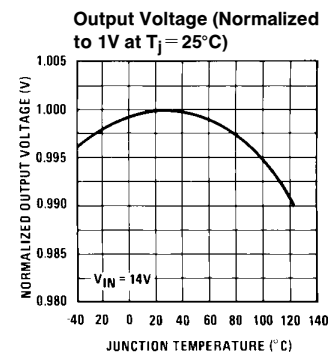
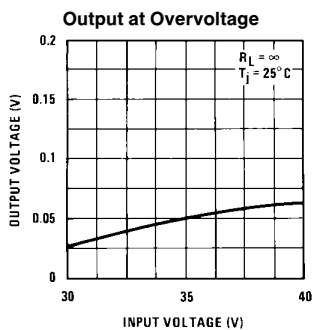
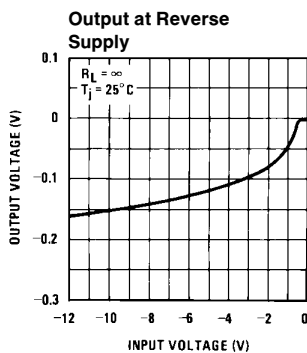
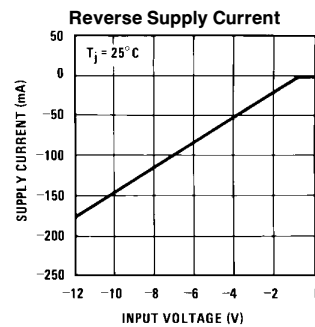
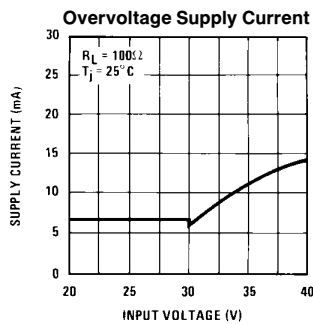
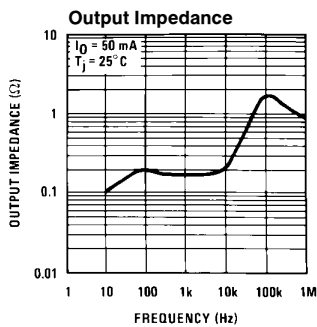


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\*Required if regulator is located far from power supply filter.

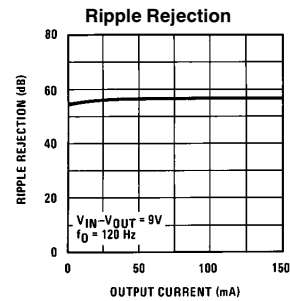
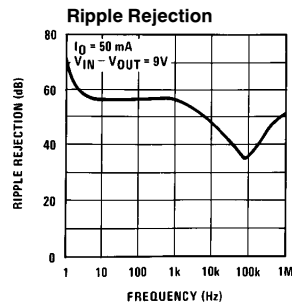
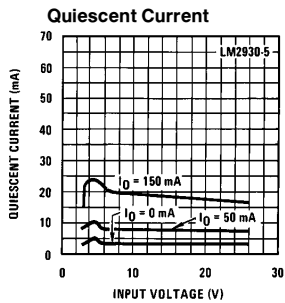
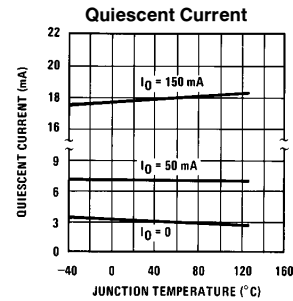
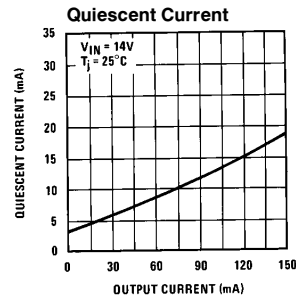
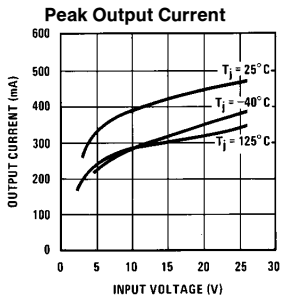
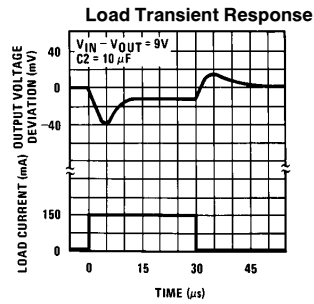
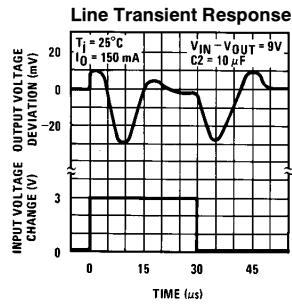
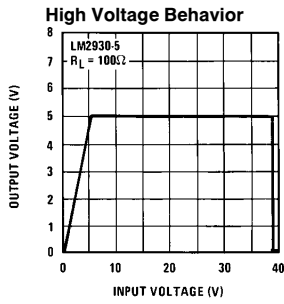
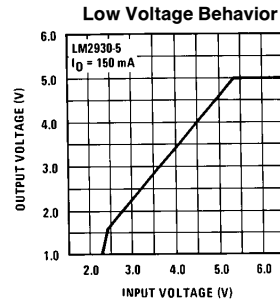
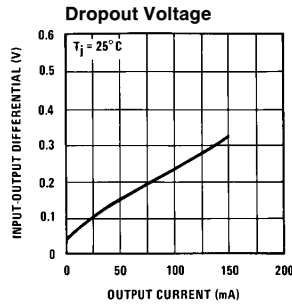
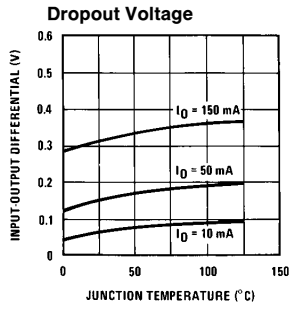
\*\* $C_{OUT}$  must be at least 10  $\mu$ F to maintain stability. May be increased without bound to maintain regulation during transients. Locate as close as possible to the regulator. This capacitor must be rated over the same operating temperature range as the regulator. The equivalent series resistance (ESR) of this capacitor should be less than 1 $\Omega$  over the expected operating temperature range.

## Typical Performance Characteristics



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## Typical Performance Characteristics (Continued)



TL/H/5539-2

## Definition of Terms

**Dropout Voltage:** The input-output voltage differential at which the circuit ceases to regulate against further reduction in input voltage. Measured when the output voltage has dropped 100 mV from the nominal value obtained at 14V input, dropout voltage is dependent upon load current and junction temperature.

**Input Voltage:** The DC voltage applied to the input terminals with respect to ground.

**Input-Output Differential:** The voltage difference between the unregulated input voltage and the regulated output voltage for which the regulator will operate.

**Line Regulation:** The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

**Load Regulation:** The change in output voltage for a change in load current at constant chip temperature.

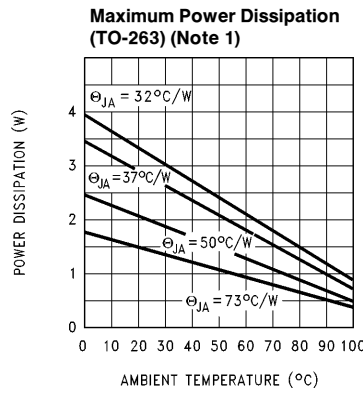
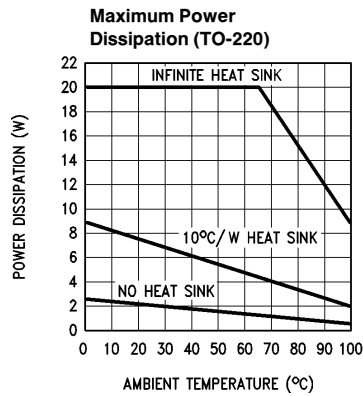
**Long Term Stability:** Output voltage stability under accelerated life-test conditions after 1000 hours with maximum rated voltage and junction temperature.

**Output Noise Voltage:** The rms AC voltage at the output, with constant load and no input ripple, measured over a specified frequency range.

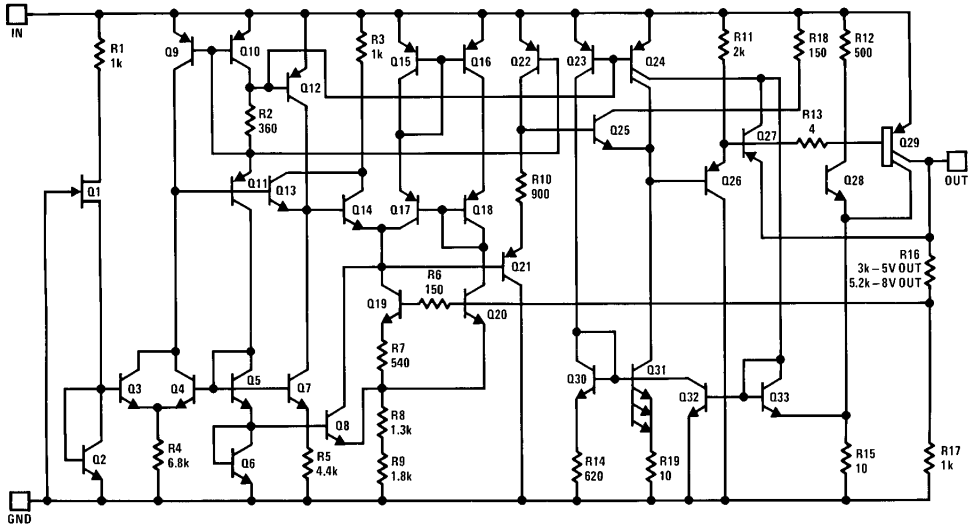
**Quiescent Current:** That part of the positive input current that does not contribute to the positive load current. The regulator ground lead current.

**Ripple Rejection:** The ratio of the peak-to-peak input ripple voltage to the peak-to-peak output ripple voltage.

**Temperature Stability of  $V_O$ :** The percentage change in output voltage for a thermal variation from room temperature to either temperature extreme.

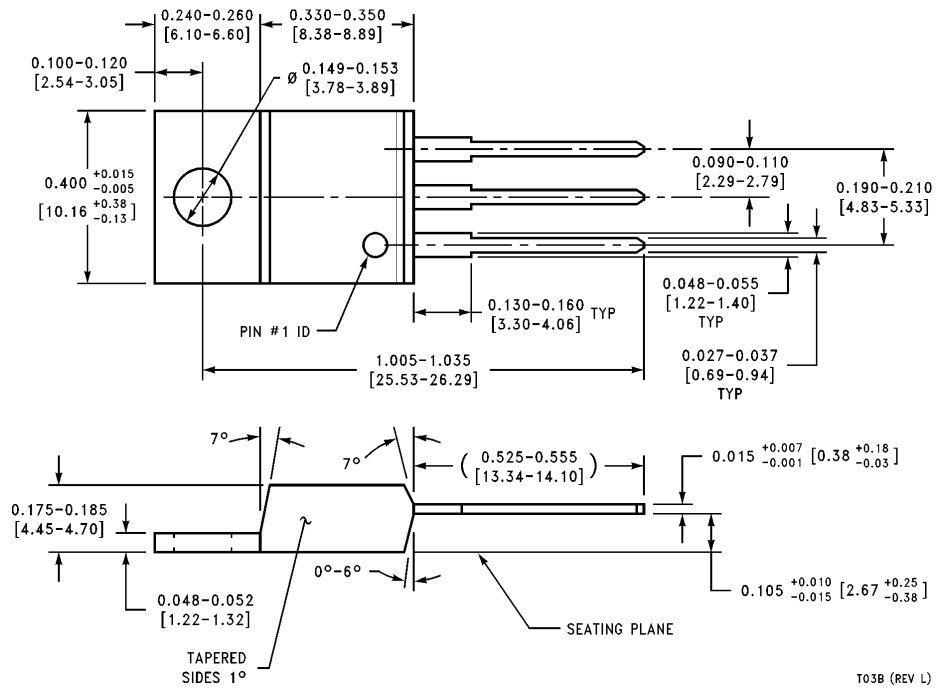


# Schematic Diagram



TL/H/5539-10

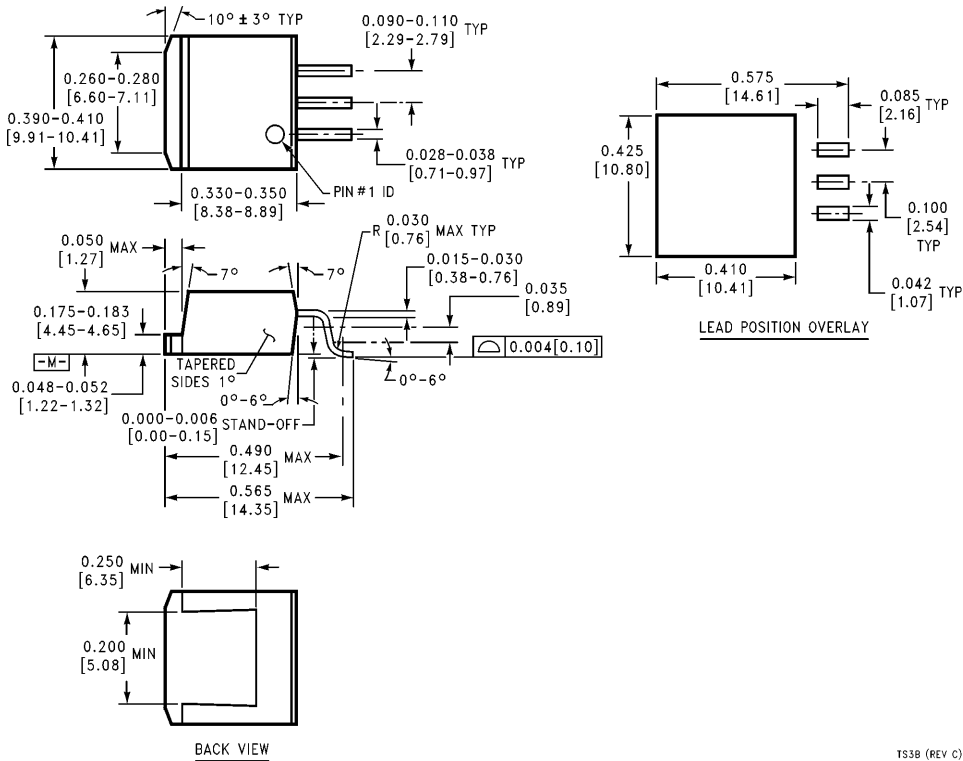
**Physical Dimensions** inches (millimeters)



**TO-220 3-Lead Molded Package**  
**Order Number LM2930T-5.0 or LM2930T-8.0**  
**NS Package Number T03B**

T03B (REV L)

**Physical Dimensions** inches (millimeters) (Continued)



**TO-263 3-Lead Plastic Surface Mount Package**  
**Order Number LM2930S-5.0 or LM2930S-8.0**  
**NS Package Number TS3B**

TS3B (REV C)

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